

National Semiconductor

November 1994

54F/74F190 **Up/Down Decade Counter with Preset and Ripple Clock**

General Description

The 'F190 is a reversible BCD (8421) decade counter featuring synchronous counting and asynchronous presetting. The preset feature allows the 'F190 to be used in programmable dividers. The Count Enable input, the Terminal Count output and the Ripple Clock output make possible a variety of methods of implementing multistage counters. In the counting modes, state changes are initiated by the rising edge of the clock.

Features

- High-speed—125 MHz typical count frequency
- Synchronous counting
- Asynchronous parallel load
- Cascadable

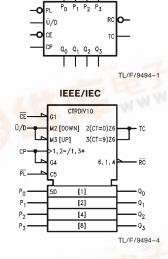
Commercial	Military	Package Number	Package Des <mark>cription</mark>
74F190PC		N16E	16-Lead (0.300" Wide) Molded Dual-In-Line
	54F190DM (Note 2)	J16A	16- <mark>Lead Cerami</mark> c Dual-In-Line
74F190SC (Note 1)		M16A	16-Lead (0.150" Wide) Molded Small Outline, JEDEC
	54F190FM (Note 2)	W16A	16-Lead Cerpack
- 44 (45)	54F190LM (Note 2)	E20A	20-Lead Ceramic Leadless Chip Carrier, Type C

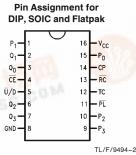
Note 1: Devices also available in 13" reel. Use suffix = SCX.

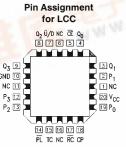
Note 2: Military grade device with environmental and burn-in processing. Use suffix = DMQB, FMQB and LMQB.

Logic Symbols

Connection Diagrams







TL/F/9494-3

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Unit Loading/Fan Out

		54F/74F			
Pin Names	Description	U.L. HIGH/LOW	Input I _{IH} /I _{IL} Output I _{OH} /I _{OL}		
CE	Count Enable Input (Active LOW)	1.0/3.0	20 μA/-1.8 mA		
CP	Clock Pulse Input (Active Rising Edge)	1.0/1.0	20 μA/ - 0.6 mA		
P ₀ -P ₃	Parallel Data Inputs	1.0/1.0	20 μA/ – 0.6 mA		
PL	Asynchronous Parallel Load Input (Active LOW)	1.0/1.0	20 μA/ – 0.6 mA		
Ū/D	Up/Down Count Control Input	1.0/1.0	20 μA/ – 0.6 mA		
$Q_0 - Q_3$	Flip-Flop Outputs	50/33.3	-1 mA/20 mA		
RC	Ripple Clock Output (Active LOW)	50/33.3	-1 mA/20 mA		
TC	Terminal Count Output (Active HIGH)	50/33.3	-1 mA/20 mA		

Functional Description

The 'F190 is a synchronous up/down BCD decade counter containing four edge-triggered flip-flops, with internal gating and steering logic to provide individual preset, count-up and count-down operations. It has an asynchronous parallel load capability permitting the counter to be preset to any desired number. When the Parallel Load (PL) input is LOW, information present on the Parallel Data inputs (P0-P3) is loaded into the counter and appears on the Q outputs. This operation overrides the counting functions, as indicated in the Mode Select Table. A HIGH signal on the $\overline{\text{CE}}$ input inhibits counting. When $\overline{\text{CE}}$ is LOW, internal state changes are initiated synchronously by the LOW-to-HIGH transition of the clock input. The direction of counting is determined by the \overline{U}/D input signal, as indicated in the Mode Select Table, $\overline{\text{CE}}$ and $\overline{\text{U}}/\text{D}$ can be changed with the clock in either state, provided only that the recommended setup and hold times are observed.

RC Truth Table

	Inputs		Output
CE	TC*	СР	RC
L	Н	T	T
Н	X	X	Н
×	L	X	Н

*TC is generated internally

H = HIGH Voltage Level

L = LOW Voltage Level

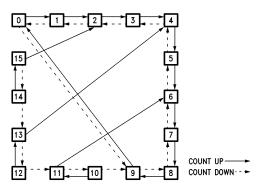
X = Immaterial

Two types of outputs are provided as overflow/underflow indicators. The Terminal Count (TC) output is normally LOW and goes HIGH when a circuit reaches zero in the countdown mode or reaches 9 in the count-up mode. The TC output will then remain HIGH until a state change occurs, whether by counting or presetting or until \overline{U}/D is changed. The TC output should not be used as a clock signal because it is subject to decoding spikes. The TC signal is also used internally to enable the Ripple Clock (RC) output. The RC output is normally HIGH. When CE is LOW and TC is HIGH, the RC output will go LOW when the clock next goes LOW and will stay LOW until the clock goes HIGH again. This feature simplifies the design of multistage counters. For a discussion and illustrations of the various methods of implementing multistage counters, please see the 'F191 data sheet.

Mode Select Table

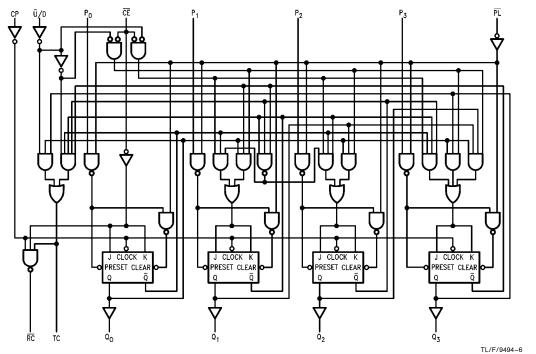
	In	puts	Mode				
PL	CE	Ū/D	CP	mode			
Н	L	L	\	Count Up			
Н	L	Н	_	Count Down			
L	Χ	Χ	Χ	Preset (Asyn.)			
Н	Н	Χ	Χ	No Change (Hold)			

State Diagram



TL/F/9494-5

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

 $\begin{array}{lll} \mbox{Storage Temperature} & -65^{\circ}\mbox{C to} + 150^{\circ}\mbox{C} \\ \mbox{Ambient Temperature under Bias} & -55^{\circ}\mbox{C to} + 125^{\circ}\mbox{C} \\ \mbox{Junction Temperature under Bias} & -55^{\circ}\mbox{C to} + 175^{\circ}\mbox{C} \\ \mbox{Plastic} & -55^{\circ}\mbox{C to} + 150^{\circ}\mbox{C} \\ \end{array}$

V_{CC} Pin Potential to

Voltage Applied to Output

in HIGH State (with $V_{CC} = 0V$)

 $\begin{array}{lll} \mbox{Standard Output} & -0.5\mbox{V to V}_{\mbox{CC}} \\ \mbox{TRI-STATE} \mbox{Output} & -0.5\mbox{V to } +5.5\mbox{V} \end{array}$

Current Applied to Output

in LOW State (Max) twice the rated I_{OL} (mA)

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

Recommended Operating Conditions

Free Air Ambient Temperature

Military $-55^{\circ}\text{C to} + 125^{\circ}\text{C}$ Commercial $0^{\circ}\text{C to} + 70^{\circ}\text{C}$

Supply Voltage Military

Military +4.5V to +5.5V Commercial +4.5V to +5.5V

DC Electrical Characteristics

Symbol	Parameter		54F/74F			Units	V _{CC}	Conditions	
Syllibol	raiaille	tei	Min	Тур	Max	Uiiis	VCC	Conditions	
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal	
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal	
V_{CD}	Input Clamp Diode Vo	oltage			-1.2	V	Min	$I_{\text{IN}} = -18 \text{ mA}$	
V _{OH}	Output HIGH Voltage	54F 10% V _{CC} 74F 10% V _{CC} 74F 5% V _{CC}	2.5 2.5 2.7			V	Min	$I_{OH} = -1 \text{ mA}$ $I_{OH} = -1 \text{ mA}$ $I_{OH} = -1 \text{ mA}$	
V_{OL}	Output LOW Voltage	54F 10% V _{CC} 74F 10% V _{CC}			0.5 0.5	٧	Min	$I_{OL} = 20 \text{ mA}$ $I_{OL} = 20 \text{ mA}$	
I _{IH}	Input HIGH Current	54F 74F			20.0 5.0	μΑ	Max	$V_{IN} = 2.7V$	
I _{BVI}	Input HIGH Current Breakdown Test	54F 74F			100 7.0	μΑ	Max	V _{IN} = 7.0V	
I _{CEX}	Output HIGH Leakage Current	54F 74F			250 50	μΑ	Max	$V_{OUT} = V_{CC}$	
V_{ID}	Input Leakage Test	74F	4.75			٧	0.0	$I_{\text{ID}}=1.9~\mu\text{A}$ All Other Pins Grounded	
I _{OD}	Output Leakage Circuit Current	74F			3.75	μΑ	0.0	V _{IOD} = 150 mV All Other Pins Grounded	
I _{IL}	Input LOW Current				-0.6 -1.8	mA	Max	$V_{IN} = 0.5V$, except \overline{CE} $V_{IN} = 0.5V$, \overline{CE}	
los	Output Short-Circuit (Current	-60		-150	mA	Max	V _{OUT} = 0V	
I _{CCL}	Power Supply Curren	t		38	55	mA	Max	$V_O = LOW$	

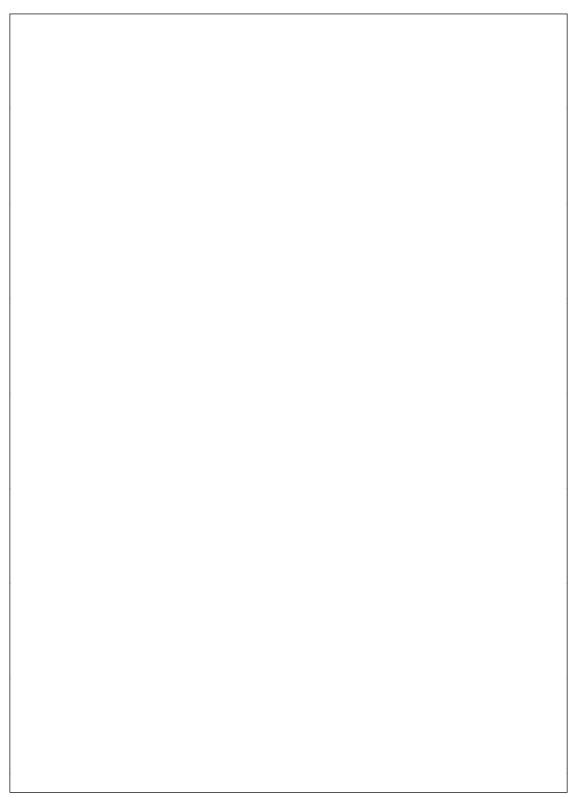
AC Electrical Characteristics

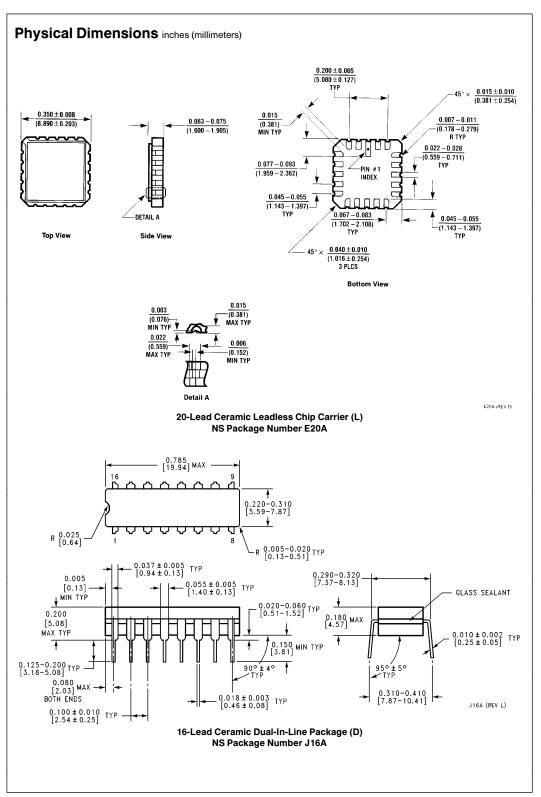
		$74F$ $T_{A} = +25^{\circ}C$ $V_{CC} = +5.0V$ $C_{L} = 50 \text{ pF}$			54F T _A , V _{CC} = Mil C _L = 50 pF		74F T _A , V _{CC} = Com C _L = 50 pF		Units
Symbol	Parameter								
		Min	Тур	Max	Min	Max	Min	Max	
f _{max}	Maximum Clock Frequency	100	125		75		90		MHz
t _{PLH} t _{PHL}	Propagation Delay CP to Q _n	3.0 5.0	5.5 8.5	7.5 11.0	3.0 5.0	9.5 13.5	3.0 5.0	8.5 12.0	ns
t _{PLH} t _{PHL}	Propagation Delay CP to TC	6.0 5.0	10.0 8.5	13.0 11.0	6.0 5.0	16.5 13.5	6.0 5.0	14.0 12.0	
t _{PLH}	Propagation Delay CP to RC	3.0 3.0	5.5 5.0	7.5 7.0	3.0 3.0	9.5 9.0	3.0 3.0	8.5 8.0	ne
t _{PLH}	Propagation Delay CE to RC	3.0 3.0	5.0 5.5	7.0 7.0	3.0 3.0	9.0 9.0	3.0 3.0	8.0 8.0	ns
t _{PLH}	Propagation Delay U/D to RC	7.0 5.5	11.0 9.0	18.0 12.0	7.0 5.5	22.0 14.0	7.0 5.5	20.0 13.0	ns
t _{PLH} t _{PHL}	Propagation Delay U/D to TC	4.0 4.0	7.0 6.5	10.0 10.0	4.0 4.0	13.5 12.5	4.0 4.0	11.0 11.0	113
t _{PLH}	Propagation Delay P _n to Q _n	3.0 6.0	4.5 10.0	7.0 13.0	3.0 6.0	9.0 16.0	3.0 6.0	8.0 14.0	ns
t _{PLH}	Propagation Delay PL to Qn	5.0 5.5	8.5 9.0	11.0 12.0	5.0 5.5	13.0 14.5	5.0 5.5	12.0 13.0	ns

AC Operating Requirements

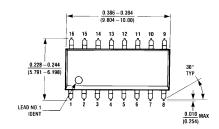
		$74F$ $T_A = +25^{\circ}C$ $V_{CC} = +5.0V$		54	ŀF	74F		
Symbol	Parameter			T _A , V _{CC} = Mil		T _A , V _{CC} = Com		Units
		Min	Max	Min	Max	Min	Max	
t _s (H) t _s (L)	Setup Time, HIGH or LOW	4.5 4.5		6.0 6.0		5.0 5.0		
t _h (H)	Hold Time, HIGH or LOW	2.0 2.0		2.0 2.0		2.0 2.0		ns
t _S (L)	Setup Time, LOW CE to CP	10.0		10.5		10.0		ns
t _h (L)	Hold Time, LOW CE to CP	0		0		0		
t _S (H) t _S (L)	Setup Time, HIGH or LOW U/D to CP	12.0 12.0		12.0 12.0		12.0 12.0		ns
t _h (H) t _h (L)	Hold Time, HIGH or LOW U/D to CP	0		0		0		
t _w (L)	PL Pulse Width, LOW	6.0		8.5		6.0		ns
t _w (L)	CP Pulse Width, LOW	5.0		7.0		5.0		ns
t _{rec}	Recovery Time PL to CP	6.0		7.5		6.0		ns

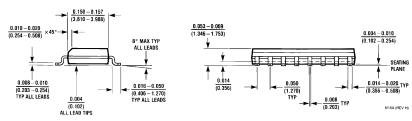
Ordering Information The device number is used to form part of a simplified purchasing code where the package type and temperature range are defined as follows: <u>74F 190 S</u> Special Variations X = Devices shipped in 13" reels QB = Military grade device with environmental and burn-in processing shipped in tubes Temperature Range Family -74F = Commercial 54F = Military Device Type Package Code P = Plastic DIP D = Ceramic DIP Temperature Range C = Commercial (0°C to +70°C) M = Military (-55°C to +125°C) F = Flatpak L = Leadless Chip Carrier (LCC) S = Small Outline SOIC JEDEC



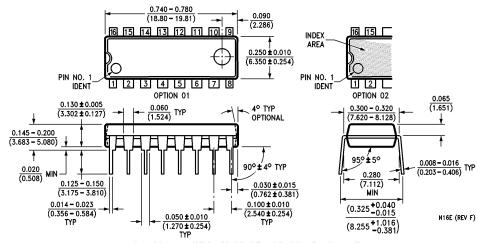


Physical Dimensions inches (millimeters) (Continued)



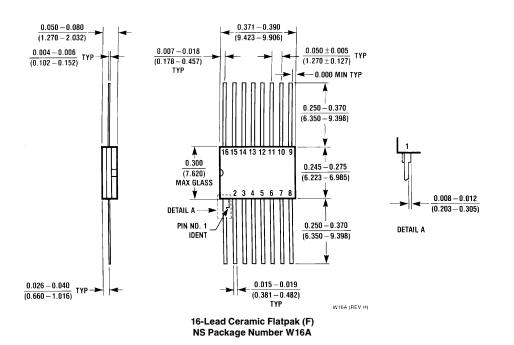


16-Lead (0.150" Wide) Molded Small Outline Package, JEDEC (S) NS Package Number M16A



16-Lead (0.300" Wide) Molded Dual-In-Line Package (P) NS Package Number N16E

Physical Dimensions inches (millimeters) (Continued)



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